

High Performance Schottky Rectifier, 180 A



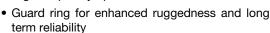


HALF-PAK (D-67)

PRIMARY CHARACTERISTICS			
I _{F(AV)} 180 A			
V_{R}	30 V		
Package	HALF-PAK (D-67)		
Circuit configuration	Single diode		

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



- · Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-182NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	180	A		
V _{RRM}		30	V		
I _{FSM}	t _p = 5 μs sine	20 000	A		
V _F	180 A _{pk} , T _J = 125 °C	0.45	V		
T _J	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-182NQ030PbF	UNITS	
Maximum DC reverse voltage	V _R	30	V	
Maximum working peak reverse voltage	V_{RWM}	- 30 v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 108 °C, rectangular waveform		180	
Maximum peak one cycle non-repetitive surge current See fig. 7		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	20 000	Α
	IFSM	10 ms sine or 6 ms rect. pulse		2500	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 18 A, L = 1 mH		162	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		36	А



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1		180 A	T _J = 25 °C	0.59	V
	V _{FM} ⁽¹⁾	360 A		0.8	
	VFM (1)	180 A	- T _J = 125 °C	0.45	
		360 A		0.65	
Maximum reverse leakage current See fig. 2	I _{RM}	T _J = 25 °C	V _R = Rated V _R	15	mA
		T _J = 125 °C		840	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		7700	pF
Typical series inductance	L _S	From top of terminal hole to mounting plane		6.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 00		10 000	V/µs

Note

⁽¹⁾ Pulse width = $500 \mu s$

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-55 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	0.28	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.05	C/VV	
Approximate weight				30	g	
				1.06	oz.	
Mounting torque	minimum		Non-lubricated threads	3 (26.5)		
Mounting torque	maximum			4 (35.4)	N · m (lbf · in)	
Terminal torque	minimum			3.4 (30)		
	maximum		5 (44.2			
Case style				HALF-PA	HALF-PAK module	

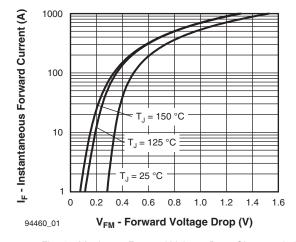


Fig. 1 - Maximum Forward Voltage Drop Characteristics

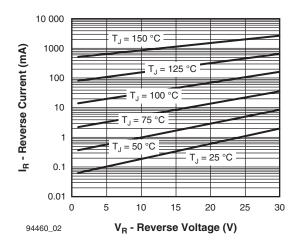


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

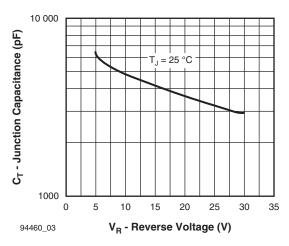


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

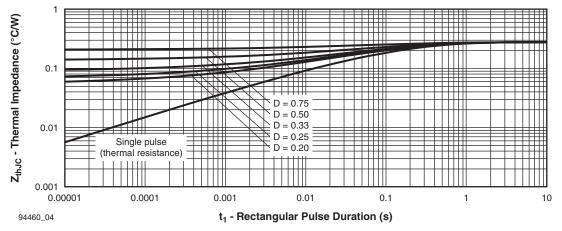


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

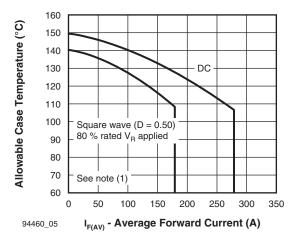


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

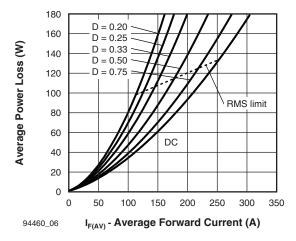


Fig. 6 - Forward Power Loss Characteristics

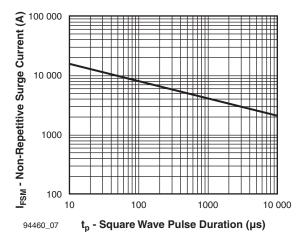


Fig. 7 - Maximum Non-Repetitive Surge Current

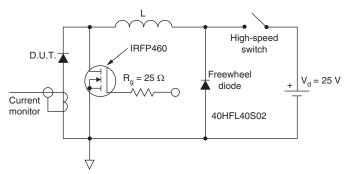


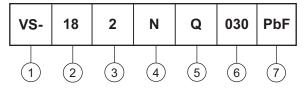
Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Average current rating (x 10)
- 3 Product silicon identification
- **4** N = not isolated
- Q = Schottky rectifier diode
- 6 Voltage rating (030 = 30 V)
- 7 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95020			



D-67 HALF-PAK

DIMENSIONS in millimeters (inches)









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